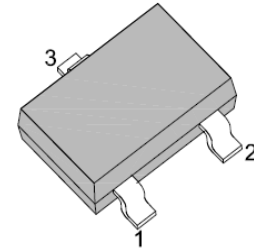


Multiple Terminals SMD Switching Diodes

Features

- Low forward voltage and low current leakage
- High speed switching application
- RoHS Compliant

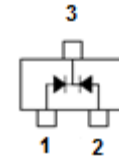


SOT-323



Mechanical Data

Case:	SOT-323, Plastic Package
Terminals:	Solderable per MIL-STD-202, Method 208
Weight:	Approx. 0.0052 gram



Maximum Ratings & Electrical Characteristics ($T_{Ambient}=25^{\circ}C$ unless noted otherwise)

Symbol	Description	BAV70WS	Unit
	Marking Code	A4/JA	
V_R	Reverse Voltage	70	V
I_F	Forward Current	200	mA
I_{FM}	Peak Forward Surge Current	500	mA
P_d	Total Device Dissipation FR-5 Board (Note 1) TA=25°C	200	mW
	Derate above 25°C	1.6	mW/°C
R_{th(JA)}	Thermal Resistance Junction to Ambient	625	°C/W
P_d	Total Device Dissipation Alumina Substrate (Note 2), TA=25°C	300	mW
	Derate above 25°C	2.4	mW/°C
R_{th(JA)}	Thermal Resistance Junction to Ambient	417	°C/W
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 to +150	°C

Note:

1. FR-5 board is 1.0"x0.75"x0.062"
2. Alumina=0.4"x0.3"x0.024" 99.5% Alumina

Electrical Characteristics ($T_{Ambient}=25^{\circ}\text{C}$ unless noted otherwise)

Symbol	Description	Min.	Max.	Unit	Conditions
$V_{(BR)R}$	Reverse Breakdown Voltage	70	-	V	$I_R=100\mu\text{A}$
V_F	Maximum Instantaneous Forward Voltage	-	0.715	V	$I_F=1\text{mA}$
		-	0.855		$I_F=10\text{mA}$
		-	1.000		$I_F=50\text{mA}$
		-	1.250		$I_F=150\text{mA}$
I_R	Maximum DC Reverse Current at Rated DC Blocking Voltage	-	60	μA	$V_R=25\text{V}$, $T_J=150^{\circ}\text{C}$
		-	2.5		$V_R=70\text{V}$
		-	100		$V_R=70\text{V}$, $T_J=150^{\circ}\text{C}$
C_T	Total Capacitance	-	1.5	pF	$V_R=0\text{V}$, $f=1\text{MHz}$
T_{rr}	Reverse Recovery Time	-	6.0	nS	$I_F=I_R=10\text{mA}$, $I_R(\text{REC})=1\text{mA}$, $V_R=5.0\text{V}$ $R_L=100\Omega$

Typical Characteristics Curves

Fig1- Typical Forward Characteristics

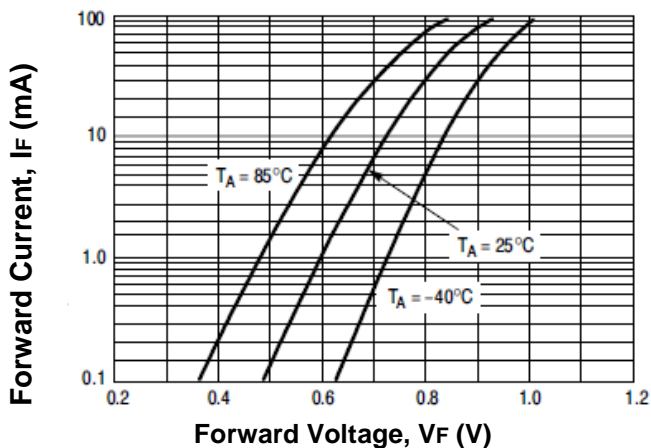


Fig.2- Typical Reverse Characteristics

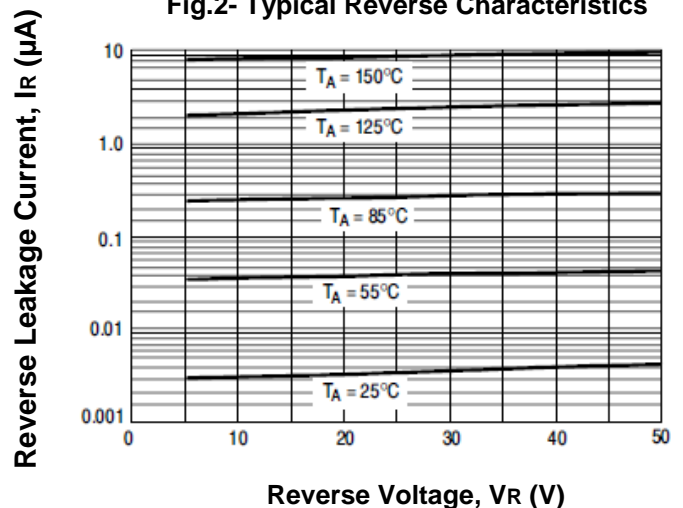


Fig.3- Typical Junction Capacitance

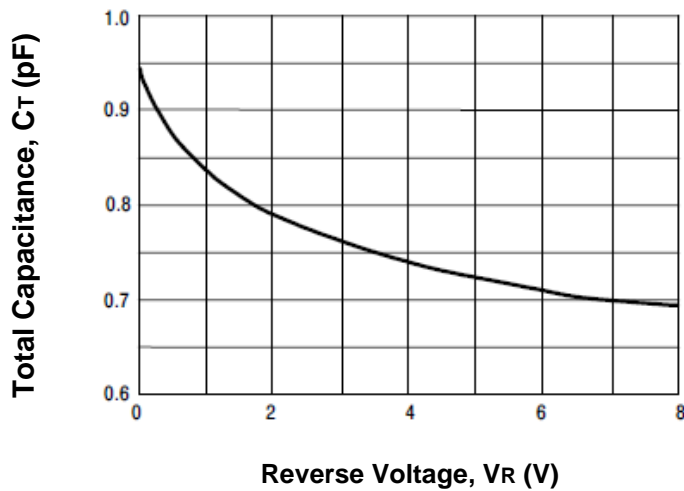
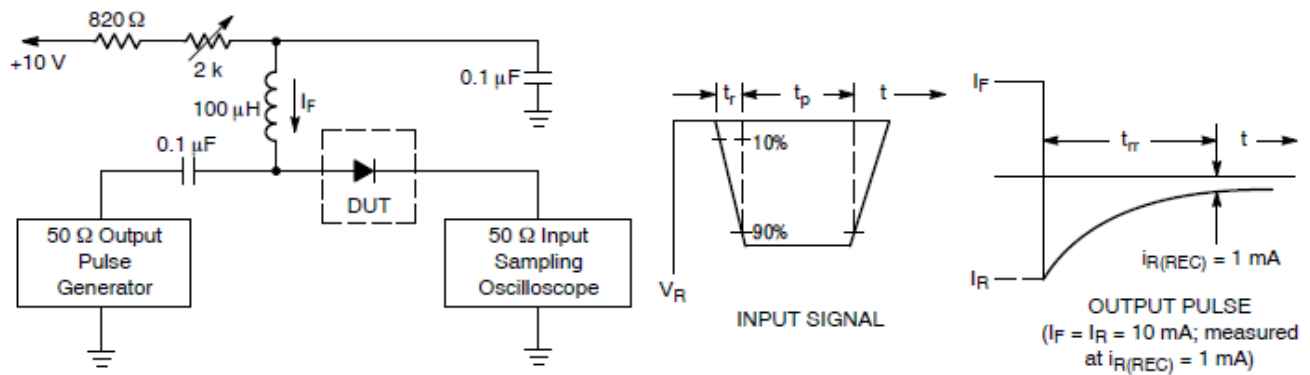
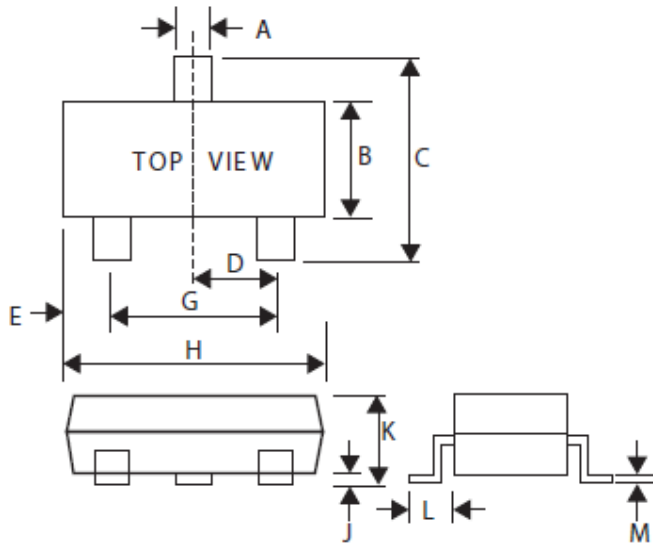


Fig.4- Recovery Time Equivalent Test Circuit



- Notes: 1. A 2.0 k Ω variable resistor adjusted for a Forward Current (I_F) of 10 mA.
2. Input pulse is adjusted so $I_{R(peak)}$ is equal to 10 mA.
3. $t_p \gg t_{rr}$

Dimensions in mm



SOT-323		
Dim	Min	Max
A	0.30	0.40
B	1.15	1.35
C	2.00	2.40
D	-	0.65
E	0.30	0.40
G	1.20	1.40
H	1.80	2.20
J	0.00	0.10
K	0.80	1.00
L	0.42	0.53
M	0.10	0.25

SOT-323

How to contact us

US HEADQUARTERS

28040 WEST HARRISON PARKWAY, VALENCIA, CA 91355-4162

Tel: (800)-TAITRON (800)-824-8766 (661)-257-6060

Fax: (800)-TAITFAX (800)-824-8329 (661)-257-6415

Email: taitron@taitroncomponents.com

Http://www.taitroncomponents.com

TAITRON COMPONENTS MEXICO, S.A .DE C.V.

BOULEVARD CENTRAL 5000 INTERIOR 5 PARQUE INDUSTRIAL ATITALAQUIA, HIDALGO

C.P. 42970 MEXICO

Tel: +52-55-5560-1519

Fax: +52-55-5560-2190

TAITRON COMPONENTS INCORPORATED TAIWAN, TAIPEI

6F., No.190, Sec. 2, Zhongxing Rd., Xindian Dist., New Taipei City 23146, Taiwan R.O.C.

Tel: 886-2-2913-6238

Fax: 886-2-2913-6239

TAITRON COMPONENT TECHNOLOGY, SHANGHAI CORPORATION

METROBANK PLAZA, 1160 WEST YAN'AN ROAD, SUITE 1503, SHANGHAI, 200052, CHINA

Tel: +86-21-5424-9942

Fax: +86-21-2302-5027